

EAST Search History**EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode near outside near display)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 09:34
S1	2	"20020130983"	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:04
S2	2	"5851918".pn.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:05
S3	2	"5742074".pn.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:06
S4	2	"6587160".pn.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:07

S5	:2	"5742074".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:10
S6	:2	"5492074".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:11
S7	:2	"5492582".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:11
S8	:2	"6016174".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:13
S9	:42	(349/43,42,139,147,158,138,122,149,150,151,152.cls.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and passivation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:30
S10	:1	(349/43,42,139,147,158,138,122,149,150,151,152.cls.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and passivation and exfoliation	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:32

S11	:0	(349/43,42,139,147,158,138,122,149,150,151,152.ccls.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:33
S12	:1	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:34
S13	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near (beneath or under) near (electrode or metallic or metal)) and passivation	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:35
S14	:2	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (first near (metal or metallic) near line) and (second near (metal or metallic) near line)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:36
S15	:57	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (terminal near electrode)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:37
S16	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and ((terminal near electrode) near extend near (metal or metallic))	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:38

S17	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:39
S18	:790	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:39
S19	:34	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2010/09/21 08:40

EAST Search History (Interference)

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near layer) and (contact near hole) and (terminal near electrode near outside near display)	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L3	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L4	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and (insulating near interposed near (conductive or electric))	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L5	:0	(tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35
L6	:0	(349/43,42,139,147,158,138,122,149,150,151,152.ccls.) and (tft or (thin near film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near between near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35

L7	0	((tft or (thin film near transistor)) and substrate and (switching near pixel) and ((insulating near layer) near (beneath or under) near (electrode or metallic or metal)) and passivation	USPAT; UPAD	OR	OFF	2010/09/21 09:35
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